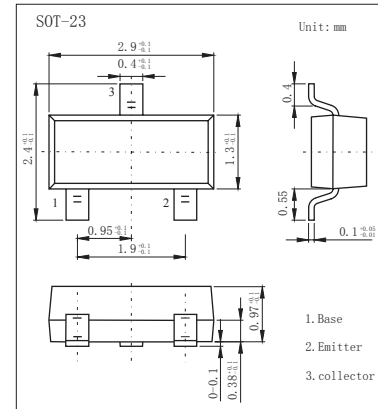


NPN Transistors

2SC2412 (2SC2412K)

Features

- Low Cob.Cob=2.0pF (Typ.)



Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V _{CB0}	60	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	7	V
Collector current	I _c	0.15	A
Collector power dissipation	P _c	0.2	W
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V _{CB0}	I _c = 50 μA, I _E = 0	60			V
Collector- emitter breakdown voltage	V _{CEO}	I _c = 1 mA, I _B = 0	50			
Emitter - base breakdown voltage	V _{EBO}	I _E = 50 μA, I _C = 0	7			
Collector-base cut-off current	I _{CB0}	V _{CB} = 60 V, I _E = 0			100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 7V, I _C = 0			100	
Collector-emitter saturation voltage	V _{CE(sat)}	I _c = 50 mA, I _B = 5mA			0.4	V
Base - emitter saturation voltage	V _{BE(sat)}	I _c = 50 mA, I _B = 5mA			1.2	
DC current gain	h _{FE}	V _{CE} = 6V, I _c = 1mA	120		560	
Collector output capacitance	C _{ob}	V _{CB} = 12V, I _E = 0, f = 1MHz		2	3.5	pF
Transition frequency	f _T	V _{CE} = 12V, I _E = -2mA, f = 100MHz	80			MHz

h_{FE} Classification

Type	2SC2412/K-Q	2SC2412/K-R	2SC2412/K-S
Range	120-270	180-390	270-560
Marking	BQ	BR	BS

2SC2412 (2SC2412K)

■ Typical Characteristics

